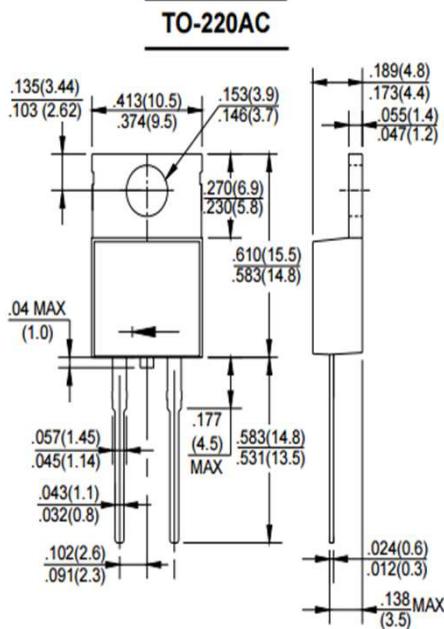


SCHOTTKY BARRIER RECTIFIERS	REVERSE VOLTAGE FORWARD CURRENT	100 10	Volts Amperes	
<b>FEATURES</b>				
<ul style="list-style-type: none"> <li>● For surface mounted application</li> <li>● Trench Schottky Technology</li> <li>● Low forward voltage drop, high efficiency</li> <li>● High current capability</li> <li>● High surge capacity</li> <li>● Plastic package has UL flammability classification 94V-0</li> <li>● For use in low voltage,high frequency inverters,free wheeling,switching power supplies, DC-DC converter, and polarity protection applications</li> </ul>				
<b>MECHANICAL DATA</b>				
<ul style="list-style-type: none"> <li>● Case: TO-220AC molded plastic</li> <li>● Polarity: As marked on the body</li> <li>● Weight: 0.08ounces,2.24 grams</li> <li>● Mounting position :Any</li> </ul>			 	
 <p>Dimensions in inches and (millimeters)</p>				
<b>MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS</b>				
Rating at 25°C ambient temperature unless otherwise specified.				
Single phase, half wave ,60Hz, resistive or inductive load.				
For capacitive load, derate current by 20%				
MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)				
CHARACTERISTICS	SYMBOL	HTR10100	UNIT	
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	100	V	
Maximum RMS Voltage	$V_{RMS}$	70	V	
Maximum DC Blocking Voltage	$V_{DC}$	100	V	
Maximum Average Forward Rectified Current ( See Fig.1)	$I_{(AV)}$	10	A	
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load	$I_{FSM}$	100	A	
Peak repetitive reverse current at $t_p = 2 \mu\text{s}$ , 1 kHz	$I_{RRM}$	1	A	
Operating Temperature Range	$T_J$	-55 to +150	°C	
Storage Temperature Range	$T_{STG}$	-55 to +175	°C	
ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)				
PARAMETER / CONDITIONS	SYMBOL	Typ	Max	UNIT
Breakdown voltage per diode	$V_{BR}$	110 (minimum)	-	V
Forward Voltage (Note1) IF=5A @ $T_J=25^\circ\text{C}$ IF=5A @ $T_J=125^\circ\text{C}$ IF=10A @ $T_J=25^\circ\text{C}$ IF=10A @ $T_J=125^\circ\text{C}$	$V_F$	0.61 0.57 0.80 0.69	0.66 0.61 0.85 0.73	V
Maximum DC Reverse Current @ $T_J=25^\circ\text{C}$ at Rated DC Bolcking Voltage @ $T_J=125^\circ\text{C}$	$I_R$	40 20		uA mA
Typical Junction Capacitance (Note2)	$C_J$	322		pF
THERMAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)				
PARAMETER	SYMBOL	Typ		UNIT
Thermal Resistance Per Diode (Note3)	$R_{\theta JC}$	3		°C/W
NOTES:1.300us pulse width,2% duty cycle. 2.Measured at 1.0 MHz and applied reverse voltage of 4.0V DC. 3.Thermal resistance junction to case.				
Preliminary				

## RATING AND CHARACTERISTIC CURVES

**HTR10100**

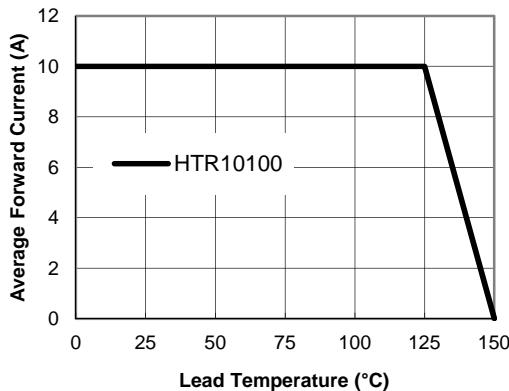


Figure 1. Forward Current Derating Curve

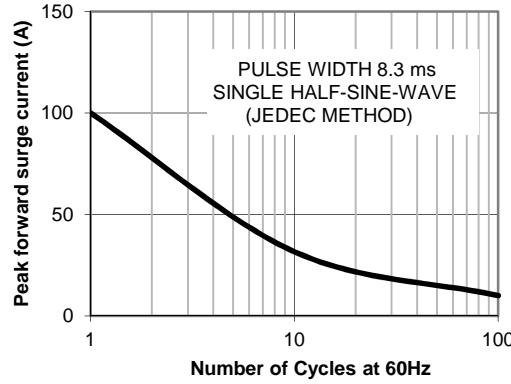


Figure 2. Maximum NON-Repetitive

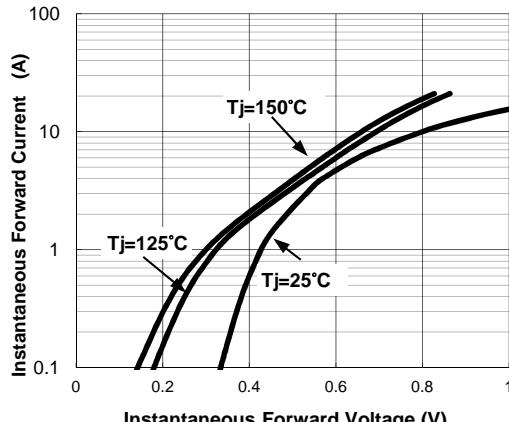


Figure 3. Typical Instantaneous Forward Characteristics Per Leg

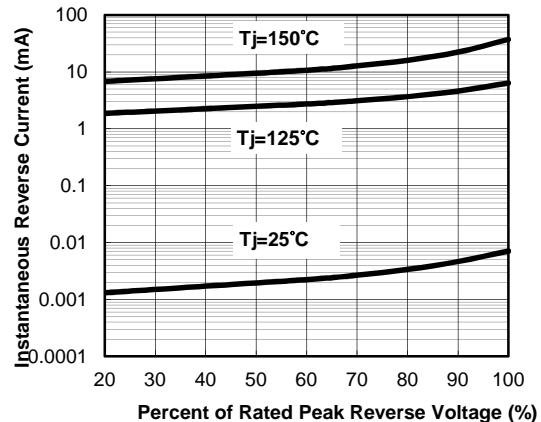


Figure 4. Typical Reverse Characteristics

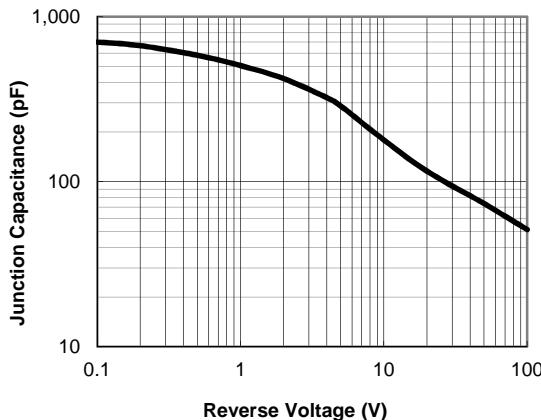


Figure 5. Typical Junction Capacitance

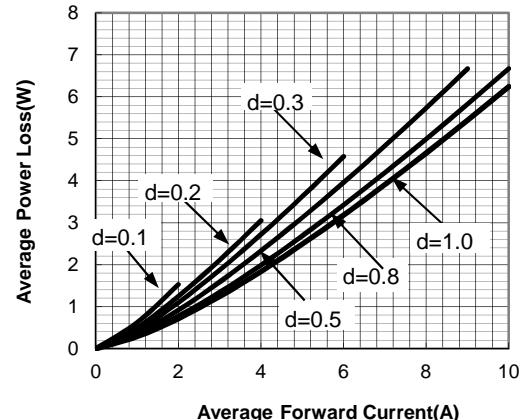


Figure 6. Forward Power Loss Characteristics